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APPLICATION NO. FILING DATE		NG DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/082,286 02/26/2002		/26/2002	Atsushi Takane	H6808.0004/P004	5346	
24998	7590	06/23/2006		EXAMINER		
		O MORIN & OS	JOHNSTON, PHILLIP A			
2101 L Stre Washington	et, NW 1, DC 2003	7	ART UNIT	PAPER NUMBER		
· ·			2881			
			DATE MAILED: 06/23/2006			

Please find below and/or attached an Office communication concerning this application or proceeding.

		Ар	plication No.	Applicant(s)					
Office Action Summary			/082,286	TAKANE ET AL.					
			aminer	Art Unit					
		Phi	llip A. Johnston	2881					
Period for	- The MAILING DATE of this communica r Reply	tion appears	on the cover sheet with the c	orrespondence ad	dress				
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).  Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).									
Status									
2a)	This action is <b>FINAL</b> . 2b)⊠ This action is non-final.								
Dispositio	on of Claims								
5)	Claim(s) 1-25 is/are pending in the application of the above claim(s) is/are valued.  Claim(s) is/are allowed.  Claim(s) 1-25 is/are rejected.  Claim(s) is/are objected to.  Claim(s) are subject to restriction  on Papers  The specification is objected to by the Entre drawing(s) filed on 26 February 2000  Applicant may not request that any objection  Replacement drawing sheet(s) including the coath or declaration is objected to be	withdrawn from and/or election and/or election and/or election is the drawn are correction is	ction requirement.  ☑ accepted or b) ☐ objecte ing(s) be held in abeyance. See s required if the drawing(s) is obj	e 37 CFR 1.85(a). lected to. See 37 Cl	FR 1.121(d).				
Priority u	nder 35 U.S.C. § 119								
<ul> <li>12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>									
2) Notice 3) Inform	(s) e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO nation Disclosure Statement(s) (PTO-1449 or PT No(s)/Mail Date		4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:	ate	O-152)				

## **Detailed Action**

1. This Office Action is submitted in response to RCE / Amendment filed 5-5-2006, wherein claims 1,24, and 25 have been amended. Claims 1-25 are pending.

## Claims Rejection - 35 U.S.C. 103

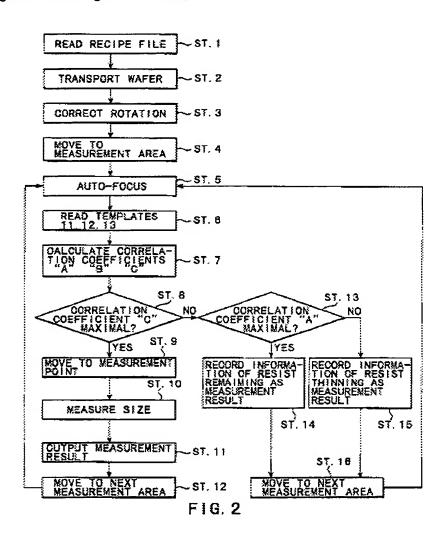
- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which the subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1-25 are rejected under 35 U.S.C. 103(a) as being unpatentable over U.S. Patent No. 6,363,167 to Miyano and Ito, U.S. Patent No. 6,108,033, in view of Lin, U.S. Patent No. 6,292,582.

Miyano (167) discloses the following:

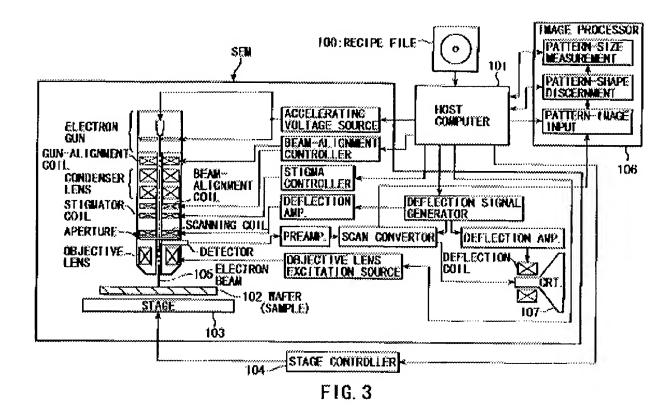
(a) The SEM, shown in Figure 3 below first scans an electron beam 105 across the measurement area and patterns present in the measurement area are processed to an SEM image. After, the templates 11 to 13 and an actual SEM image of the measurement area are read into an image processor 106, the actual SEM image is subjected to pattern matching with each of the templates 11 to 13, and correlation

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coefficients between the actual SEM image and the plurality of image templates are calculated, with the coefficients being compared to determine the maximal coefficient, which is selected as the best match. The templates 11 to 13 are made from actual SEM images on patterns or images obtained by lithography simulation from CAD data, as recited in claims 1-5,7-9,11, 24, and 25. See Column 4, line 40-67; Column 5, line 1-40; Figure 2 and Figure 3 below;



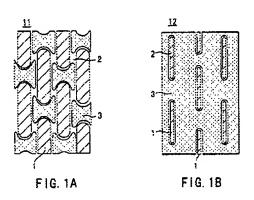
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(b) The SEM also includes storage medium 100, where information necessary for the measurement such as templates 11 to 13, measurement points which are targets for a plurality of measuring areas set on wafers in addition to the execution program is stored. The execution program, templates, other information necessary for the measurement are called a measurement recipe and the storage medium 100 in which measurement recipes are stored is called a recipe file. The recipe file 100 is prepared for each fine pattern in measurement. The use of recipe file 100 is equivalent to the capturing and inspection condition file, as recited in claims 19-23. See Column 4, line 45-58.

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- (c) Gray scale comparison is performed between an actual image and the template by subtracting a gray level in an area of the template from the gray level in the same area of the actual SEM image, as recited in claims 1,24, and 25. See Column 7, line 4-21.
- (d) The use of secondary electron images obtained from the edge 2 of a photoresist pattern and a reference numeral 3 indicates a secondary electron image obtained from a part other than the photoresist patterns (a substrate). A method in which differentiation processing on an image is performed in a designated area and a "contour" is determined to be a line which is made by connecting points in the image having the highest gradient of change in gray level, as recited in claims 12-15. See Column 4, line 33-40; Column 8, line 1-29; and Figures 1A-1C below;



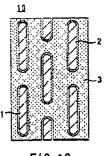


FIG. 1C

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Miyano (167) as applied above fails to teach a scanning electron microscope image, wherein a portion of the image that corresponds to the template is re-registered as a new template in place of the bitmap based on the design information, as recited in claims 1,15,24, and 25. However, Ito (033) discloses an image processing apparatus and method where an object to be monitored picked up by an image pick-up unit, including a first step for producing a difference between an input image including a background image and an image of the object to be monitored from the image pick-up unit and the background image, as an image of the object; a second step for dividing the image of the object into a plurality of parts to produce a plurality of divided images of the object as a plurality of templates, a third step for matching each of a plurality of templates with a new input image and detecting a plurality of parts of the new input image having highest degrees of matching with the templates and a fourth step for updating the new templates using the parts of the new input image having the highest degrees of matching as a plurality of new templates. The fourth step is sequentially executed for new input images to sequentially update the templates to trace the object, as recited in claims 1,15,16,24, and 25. See Column 3, line 40-57.

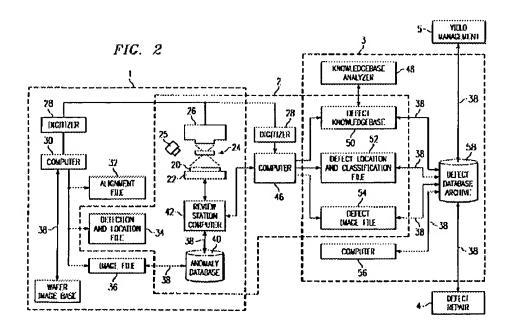
Therefore it would have been obvious to one of ordinary skill in the art that the SEM measurement system and method of Miyano (167) can be modified to use the template registering method of Ito (033), to provide sequential updating of templates so that the stable matching is attained.

The combination of Miyano (167) and Ito (033) fails to teach the use of an inspection system that includes a function to retrieve and store design data, as well as

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transmitting data to other SEM systems via a network, as recited in claims 2-7, and 10. However, Lin (582) discloses;

(a) A defect detection and locating system in Figure 2, wherein a semiconductor wafer 20 is placed on an xy stage 22 so that an area of the wafer 20 is illuminated by an energy source 25 that produces energy such as white light, darkfield light, polarized light, laser refraction, scanning electrons, focused ion beams or X-ray such that anomalies on the wafer can be detected using a microscope 24 or other sensor device. A camera 26 or other image capturing device captures the microscope's 24 image while a digitizer 28, such as a frame grabber or other means of converting the image generated by the sensor from analog to digital form, supplies a digitized (bitmap) rendering of the image to an anomaly detecting-and-locating computer 30, as recited in claims 2-7, and 19-23. See Column 4, line 61-67; and Figure 2 below;



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(b) Yield management system 5, retrieves and analyzes information from the defect database/archive 58 and other information resources available on the network 38 and from other sources such as CAD Computer-Aided Designs, results of electrical tests carried out on wafers, wafer inspection reports and images, histories of defects, process models, wafer process histories, and packaged die failure reports, as recited in claims 2,6, and 10. See Column 8, line 2-19.

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Therefore it would have been obvious to one of ordinary skill in the art that the measurement system of Miyano (167) and Ito (033) can be modified to use the resitive element forming method of Lin (582), to provide a method of storing, indexing and retrieving information, thereby providing rapid retrieval and access to the large amount of stored defect and image information so that files may be retrieved by other stations and systems connected to the network.

## Conclusion

4. Any inquiry concerning this communication or earlier communications should be directed to Phillip Johnston whose telephone number is (571) 272-2475. The examiner can normally be reached on Monday-Friday from 6:30 am to 3:00 pm. If attempts to reach the examiner by telephone are unsuccessful, the examiners supervisor John Lee can be reached at (571) 272-2477. The fax phone number for the organization where the application or proceeding is assigned is 703 872 9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

ΡJ

June 15, 2006

Mileita Wells

NIKITA WELLS

PRIMARY EXAMINER

06/16/06